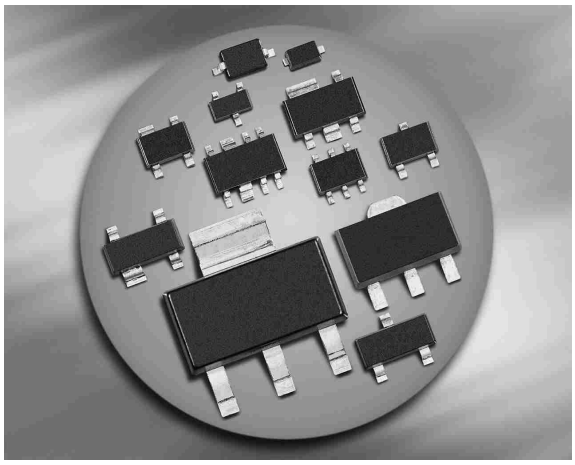
Silicon PIN Diode

- High voltage current controlled RF resistor for RF attenuator and switches
- Frequency range above 1 MHz up to 6 GHz
- Very low capacitance at zero volt reverse bias at frequencies above 1 GHz (typ. 0.17 pF)
- Low forward resistance (typ. 2.1 Ω @ 10 mA)
- Very low signal distortion
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101[1)]



AEC Qualified RoHS

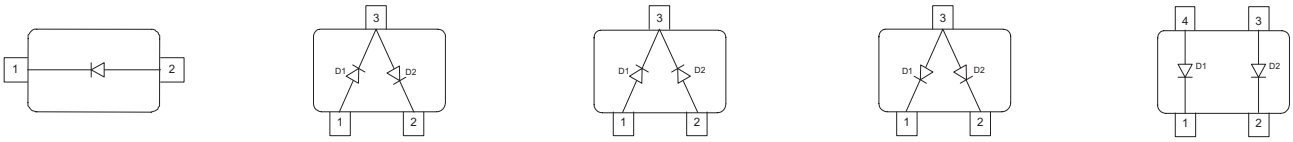
BAR64-02LRH
BAR64-02V
BAR64-03W

BAR64-04
BAR64-04W

BAR64-05
BAR64-05W

BAR64-06
BAR64-06W

BAR64-07



Type	Package	Configuration	L_S(nH)	Marking
BAR64-02LRH*	TSLP-2-7	single, leadless	0.4	O
BAR64-02V	SC79	single	0.6	O
BAR64-03W	SOD323	single	1.8	blue 2
BAR64-04	SOT23	series	1.8	PPs
BAR64-04W	SOT323	series	1.4	PPs
BAR64-05	SOT23	common cathode	1.8	PRs
BAR64-05W	SOT323	common cathode	1.4	PRs
BAR64-06	SOT23	common anode	1.8	PSs
BAR64-06W	SOT323	common anode	1.4	PSs
BAR64-07	SOT143	parallel pair	2	PTs

[1]*BAR64-02LRH is not qualified according AEC Q101

Maximum Ratings at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	150	V
Forward current	I_F	100	mA
Total power dissipation	P_{tot}		mW
BAR64-02LRH, $T_S \leq 135$ °C		250	
BAR64-02V, $T_S \leq 125$ °C		250	
BAR64-03W, BAR64-07, $T_S \leq 25$ °C		250	
BAR64-04, -05, -06, $T_S \leq 65$ °C		250	
BAR64-04W, -05W, -06W, $T_S \leq 115$ °C		250	
Junction temperature	T_j	150	°C
Operating temperature range	T_{op}	-55 ... 125	
Storage temperature	T_{stg}	-55 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point[1)]	R_{thJS}		
BAR64-02LRH		≤ 60	
BAR64-02V, -04W, -05W, -06W		≤ 140	
BAR64-03W		≤ 370	
BAR64-04, -05, -06		≤ 340	
BAR64-07		≤ 290	

Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage $I_{(BR)}$ = 5 µA	$V_{(BR)}$	150	-	-	V
Forward voltage I_F = 50 mA	V_F	-	-	1.1	

[1]For calculation of R_{thJA} please refer to Application Note Thermal Resistance

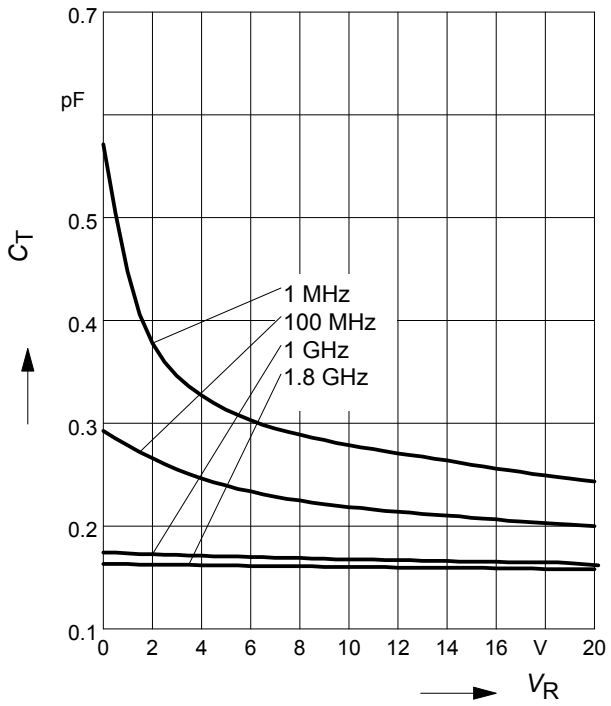
Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics					
Diode capacitance	C_T				pF
V_R = 20 V, f = 1 MHz		-	0.23	0.35	
V_R = 0 V, f = 100 MHz		-	0.3	-	
V_R = 0 V, f = 1...1.8 GHz, BAR64-02LRH		-	0.13	-	
V_R = 0 V, f = 1...1.8 GHz, all other		-	0.17	-	
Reverse parallel resistance	R_P				kΩ
V_R = 0 V, f = 100 MHz		-	10	-	
V_R = 0 V, f = 1 GHz		-	4	-	
V_R = 0 V, f = 1.8 GHz		-	3	-	
Forward resistance	r_f				Ω
I_F = 1 mA, f = 100 MHz		-	12.5	20	
I_F = 10 mA, f = 100 MHz		-	2.1	2.8	
I_F = 100 mA, f = 100 MHz		-	0.85	1.35	
Charge carrier life time I_F = 10 mA, I_R = 6 mA, measured at I_R = 3 mA, R_L = 100 Ω	τ_{rr}	-	1550	-	ns
I-region width	W_I	-	50	-	µm
Insertion loss[1)]	I_L				dB
I_F = 3 mA, f = 1.8 GHz		-	0.32	-	
I_F = 5 mA, f = 1.8 GHz		-	0.23	-	
I_F = 10 mA, f = 1.8 GHz		-	0.16	-	
Isolation[1)]	I_{SO}				
V_R = 0 V, f = 0.9 GHz		-	22	-	
V_R = 0 V, f = 1.8 GHz		-	17	-	
V_R = 0 V, f = 2.45 GHz		-	14.5	-	
V_R = 0 V, f = 5.6 GHz		-	8.5	-	

[1]BAR64-02LRH in series configuration, Z = 50 Ω

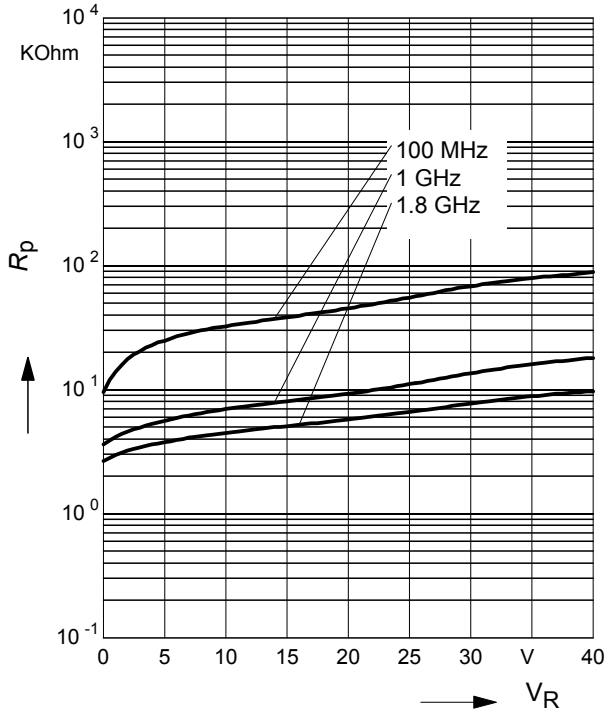
Diode capacitance $C_T = f(V_R)$

f = Parameter



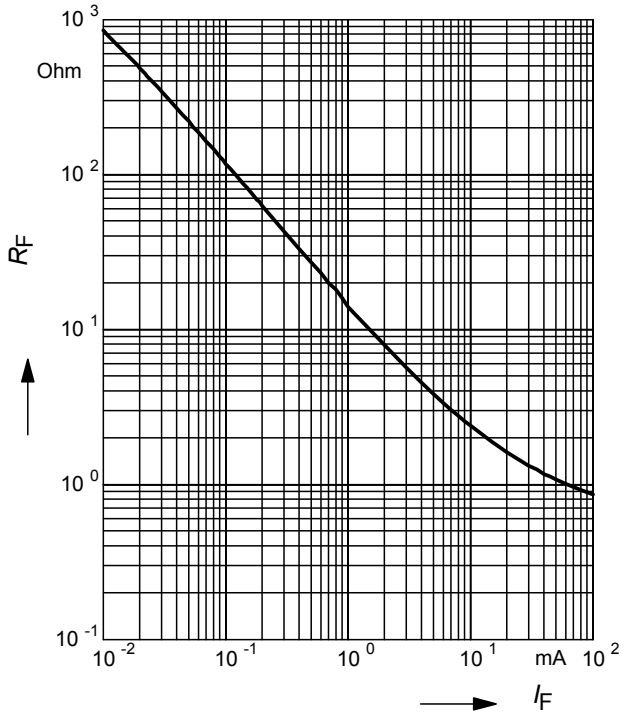
Reverse parallel resistance $R_P = f(V_R)$

f = Parameter



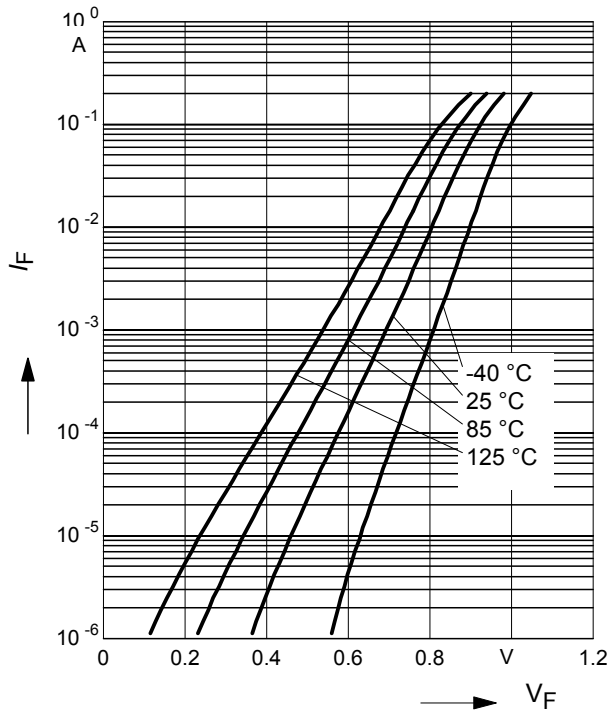
Forward resistance $r_f = f(I_F)$

f = 100MHz



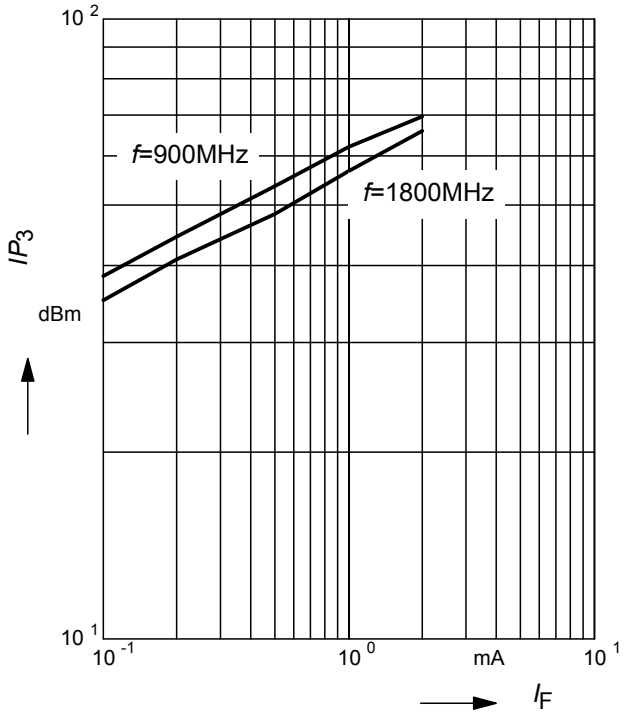
Forward current $I_F = f(V_F)$

T_A = Parameter



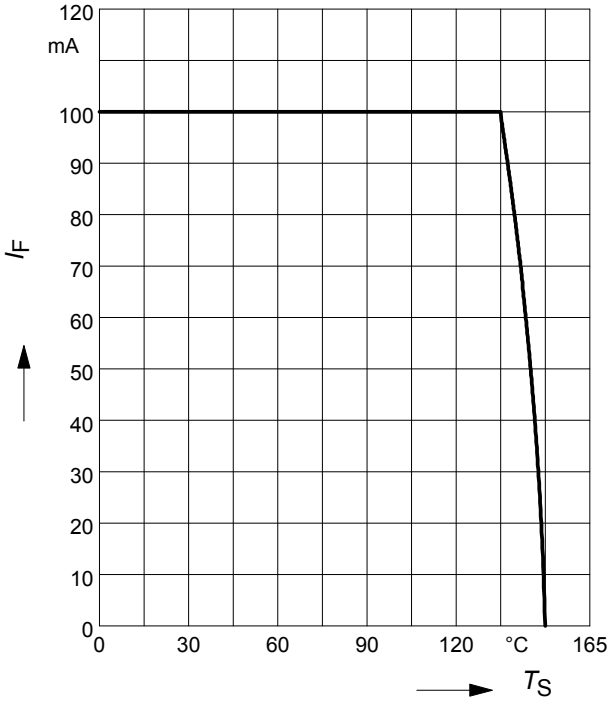
Intermodulation intercept point

$IP_3 = f(I_F)$; f = Parameter



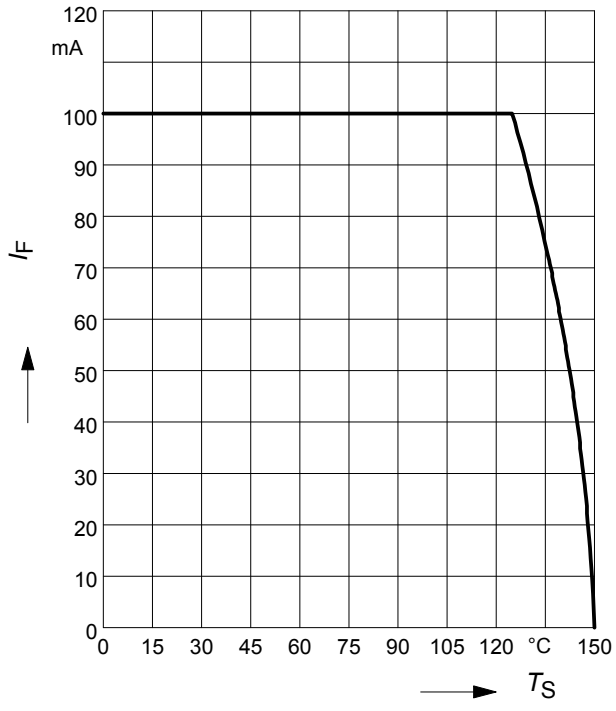
Forward current $I_F = f(T_S)$

BAR64-02LRH



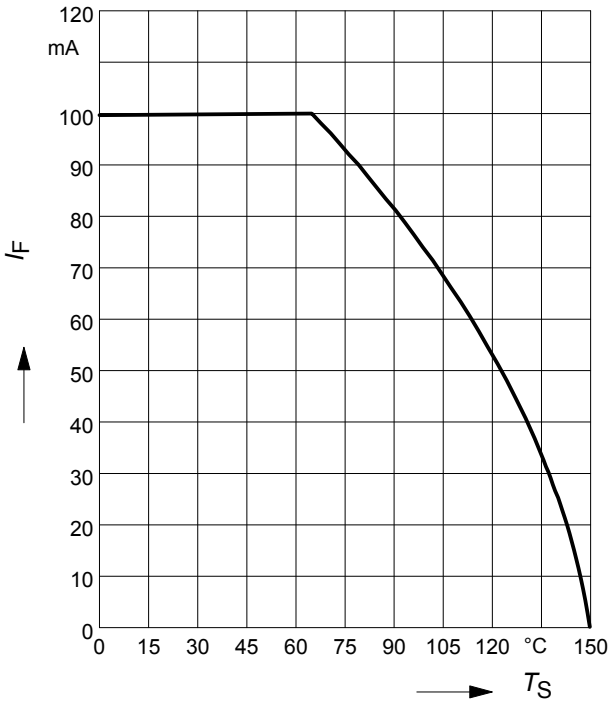
Forward current $I_F = f(T_S)$

BAR64-02V



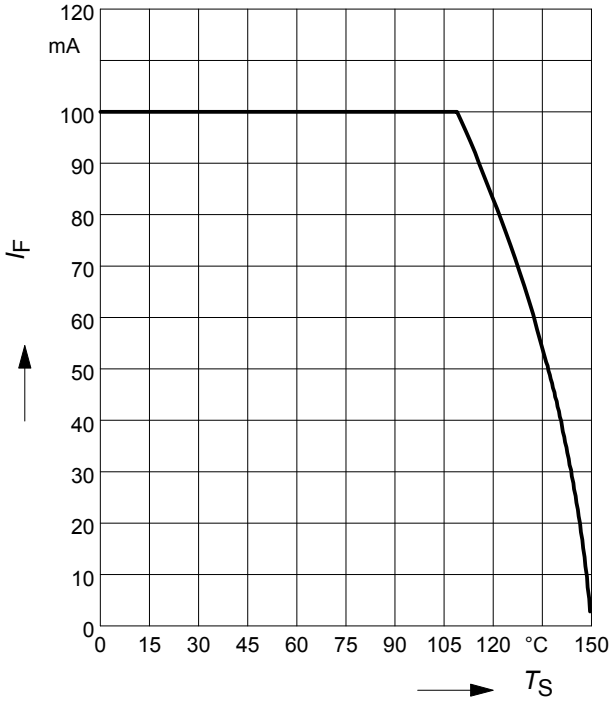
Forward current $I_F = f(T_S)$

BAR64-04, BAR64-05, BAR64-06



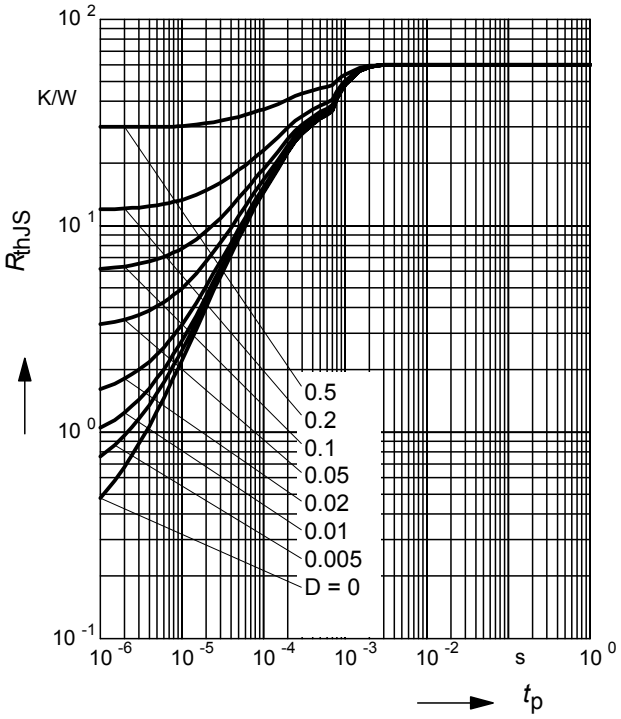
Forward current $I_F = f(T_S)$

BAR64-04W, BAR64-05W, BAR64-06W



Permissible Puls Load $R_{thJS} = f(t_p)$

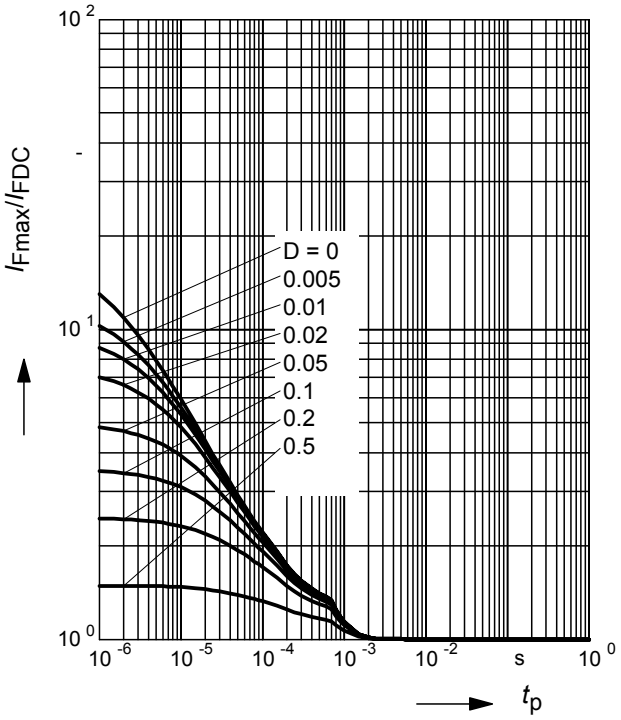
BAR64-02LRH



Permissible Pulse Load

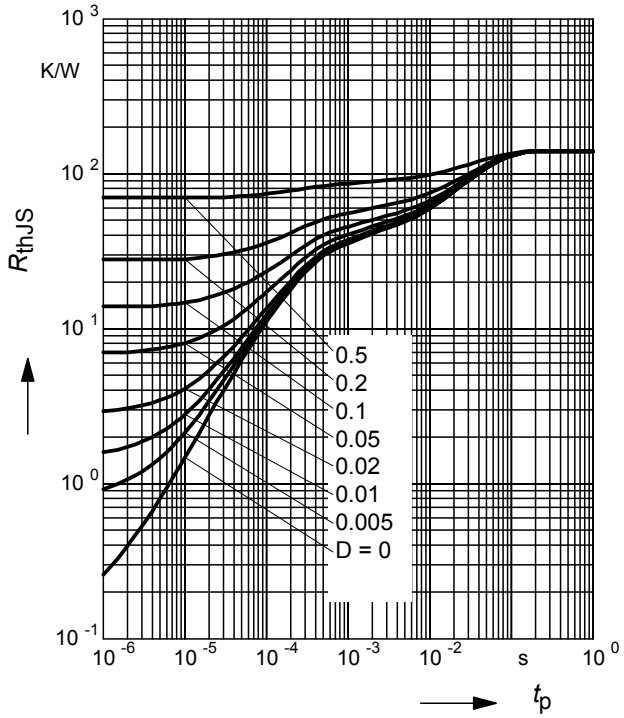
$I_{Fmax}/ I_{FDC} = f(t_p)$

BAR64-02LRH



Permissible Puls Load $R_{thJS} = f(t_p)$

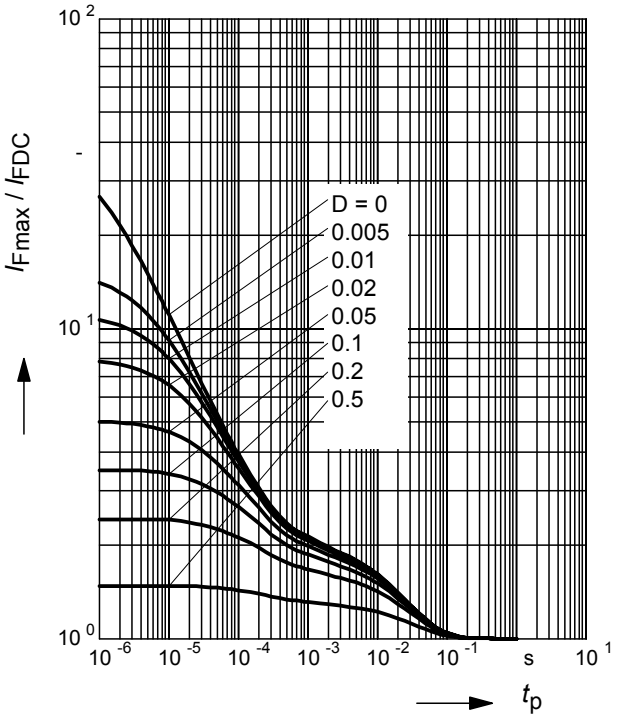
BAR64-02V



Permissible Pulse Load

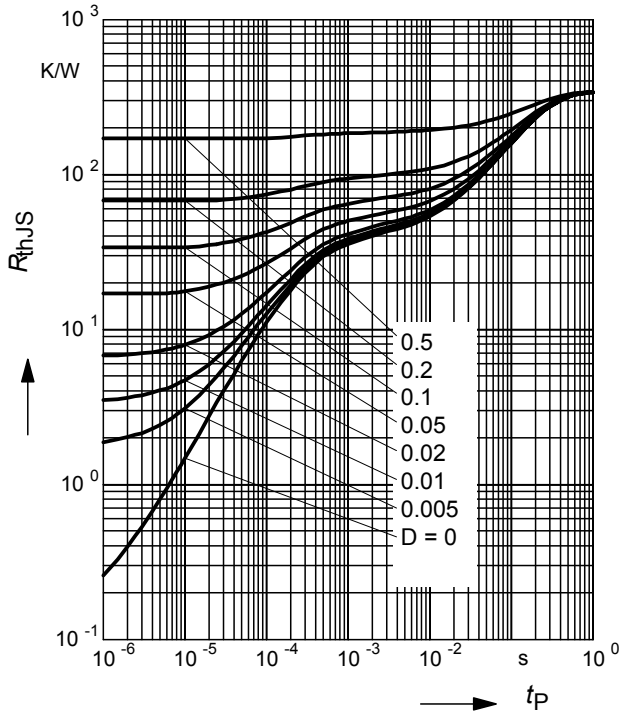
$I_{Fmax}/ I_{FDC} = f(t_p)$

BAR64-02V



Permissible Puls Load $R_{thJS} = f(t_p)$

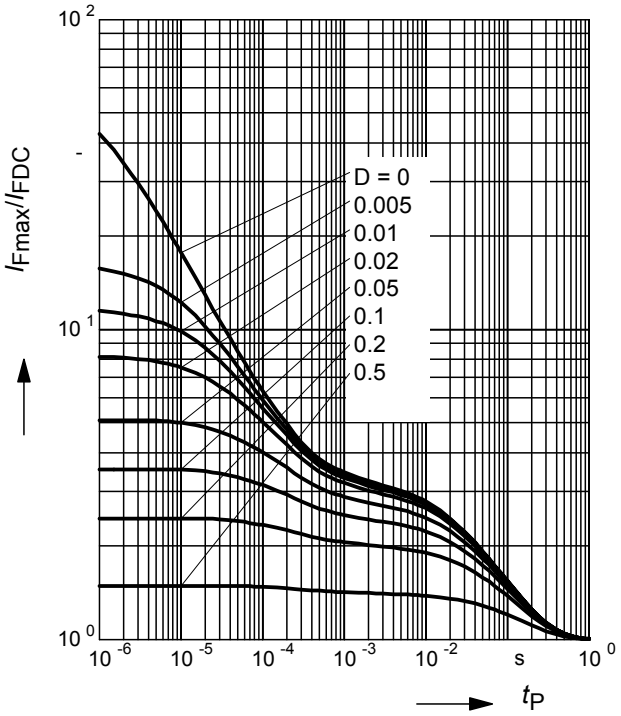
BAR64-04, BAR64-05, BAR64-06



Permissible Pulse Load

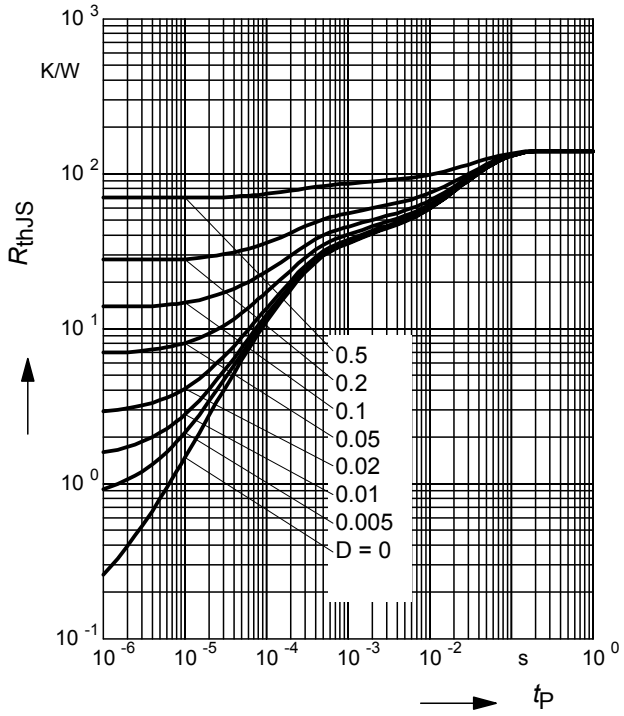
$I_{Fmax}/ I_{FDC} = f(t_p)$

BAR64-04, BAR64-05, BAR64-06



Permissible Puls Load $R_{thJS} = f(t_p)$

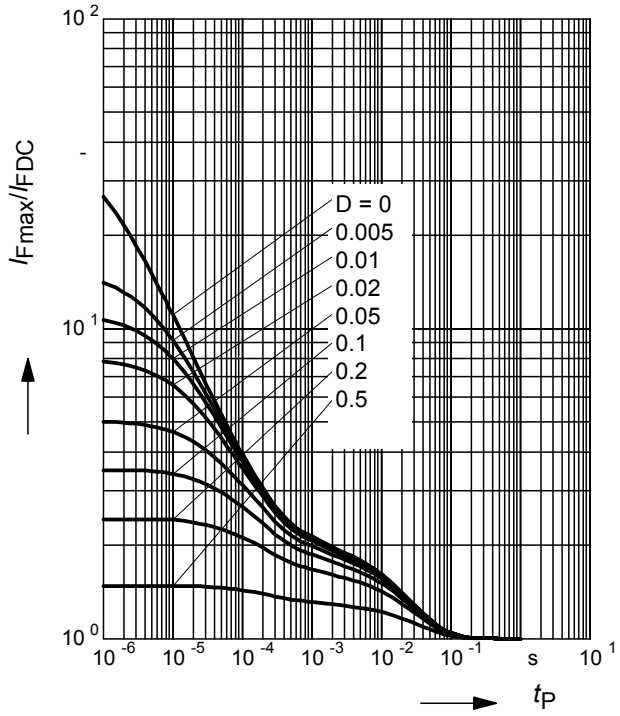
BAR64-04W, BAR64-05W, BAR64-06W



Permissible Pulse Load

$I_{Fmax}/ I_{FDC} = f(t_p)$

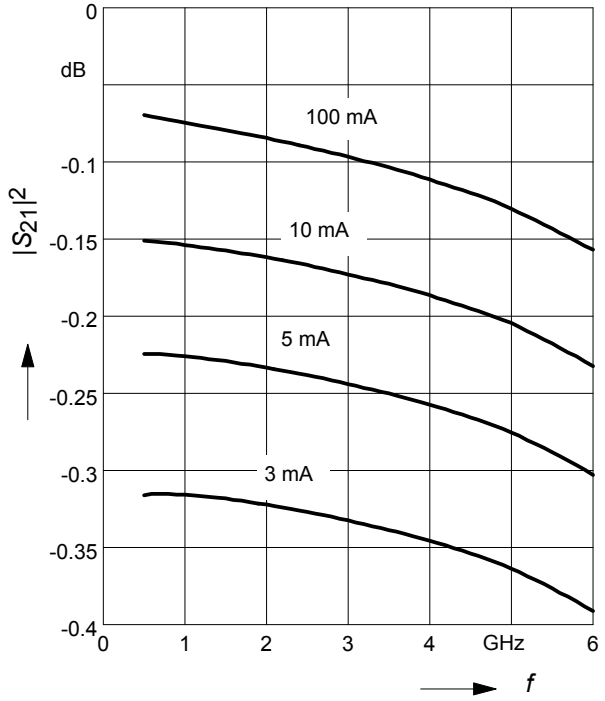
BAR64-04W, BAR64-05W, BAR64-06W



Insertion loss $I_L = -|S_{21}|^2 = f(f)$

I_F = Parameter

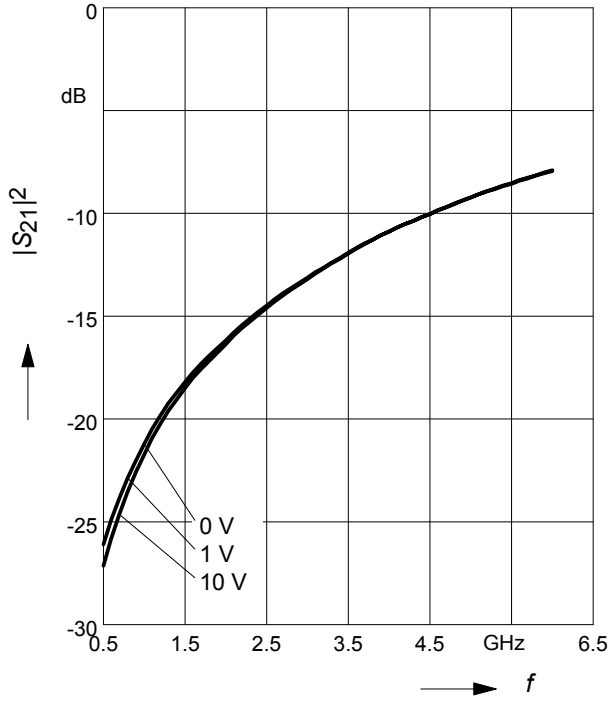
BAR64-02LRH in series configuration, $Z = 50\Omega$



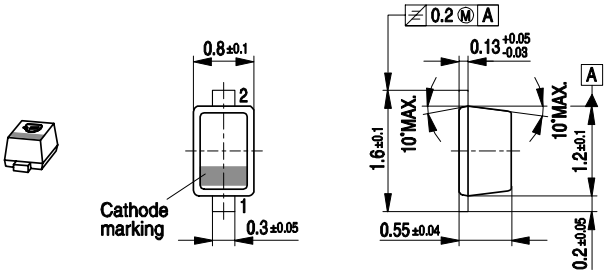
Isolation $I_{SO} = -|S_{21}|^2 = f(f)$

V_R = Parameter

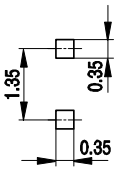
BAR64-02LRH in series configuration, $Z = 50\Omega$



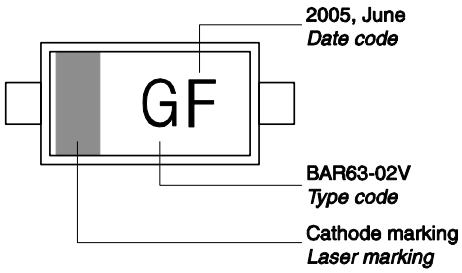
Package Outline



Foot Print

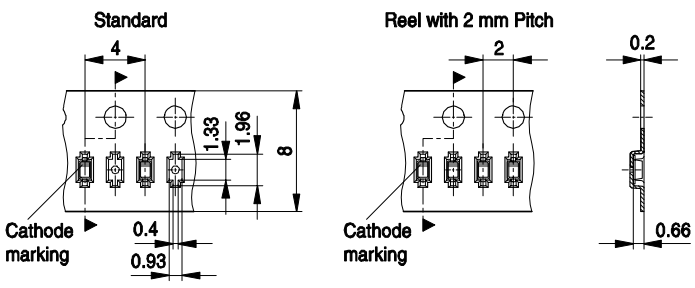


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø180 mm = 8.000 Pieces/Reel (2 mm Pitch)
Reel ø330 mm = 10.000 Pieces/Reel

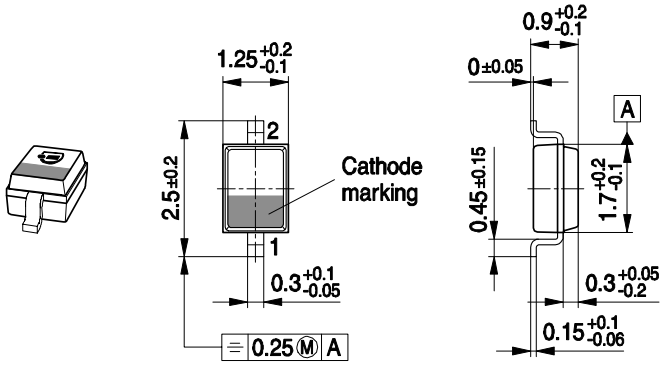


Date Code marking for discrete packages with one digit (SCD80, SC79, SC75[1)]) CES-Code

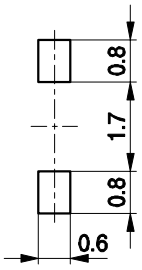
Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	a	p	A	P	a	p	A	P	a	p	A	P
02	b	q	B	Q	b	q	B	Q	b	q	B	Q
03	c	r	C	R	c	r	C	R	c	r	C	R
04	d	s	D	S	d	s	D	S	d	s	D	S
05	e	t	E	T	e	t	E	T	e	t	E	T
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	v	G	V	g	v	G	V	g	v	G	V
08	h	x	H	X	h	x	H	X	h	x	H	X
09	j	y	J	Y	j	y	J	Y	j	y	J	Y
10	k	z	K	Z	k	z	K	Z	k	z	K	Z
11	l	2	L	4	l	2	L	4	l	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

1) New Marking Layout for SC75, implemented at October 2005.

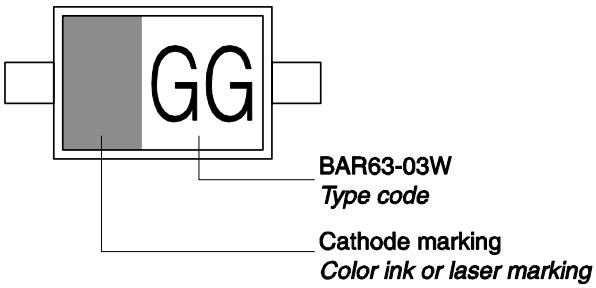
Package Outline



Foot Print

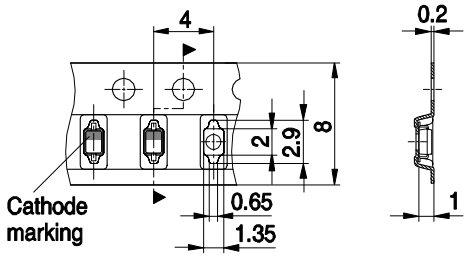


Marking Layout (Example)

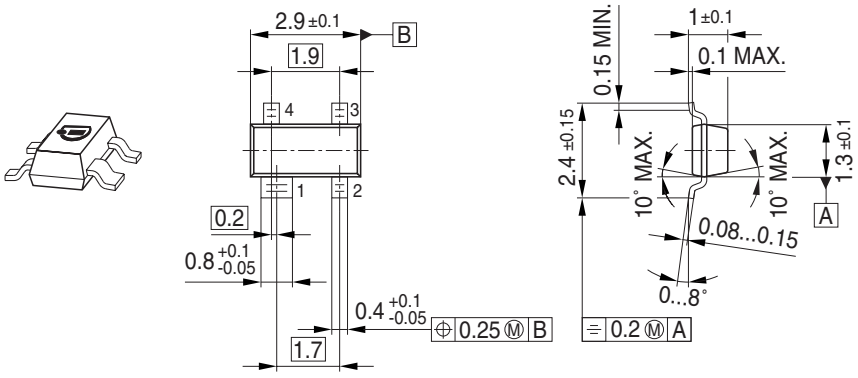


Standard Packing

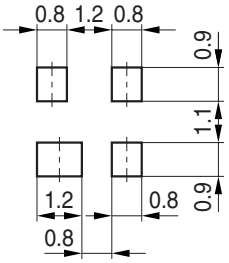
Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



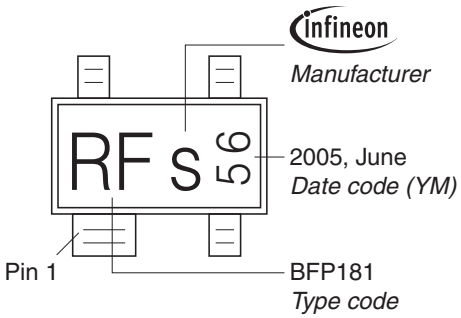
Package Outline



Foot Print

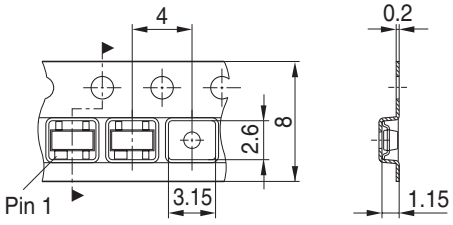


Marking Layout (Example)



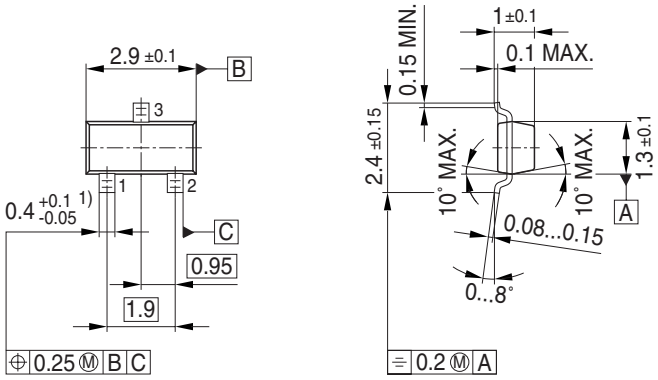
Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



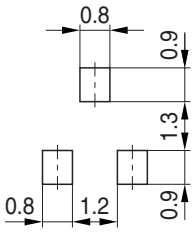
Package Outline



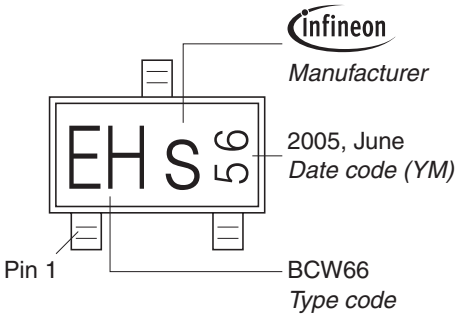


1) Lead width can be 0.6 max. in dambar area

Foot Print

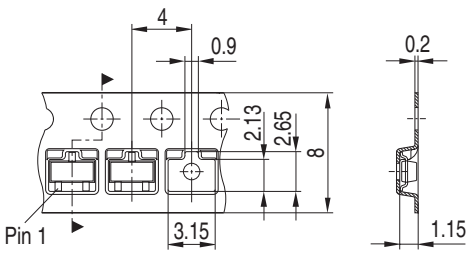


Marking Layout (Example)



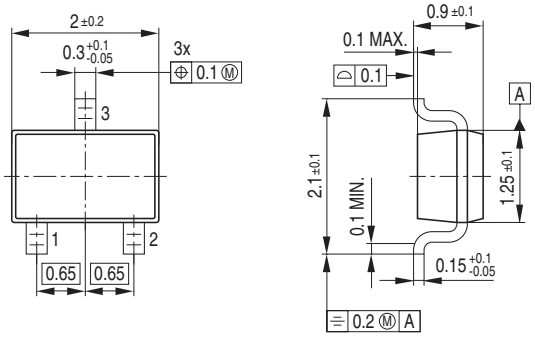
Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel

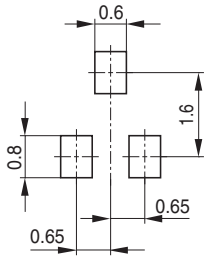


Package Outline

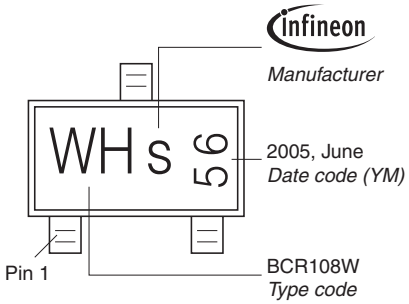




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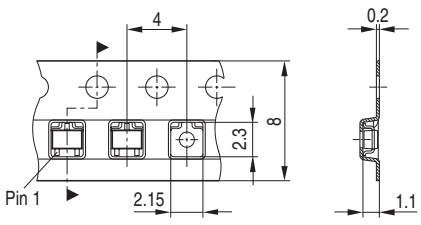


Marking Layout (Example)

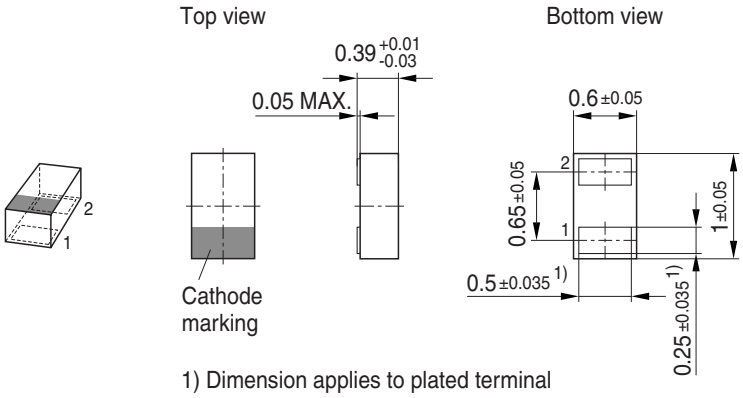


Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



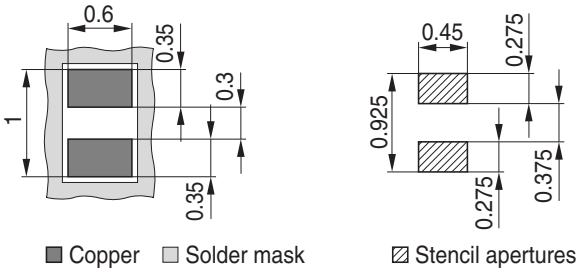
Package Outline



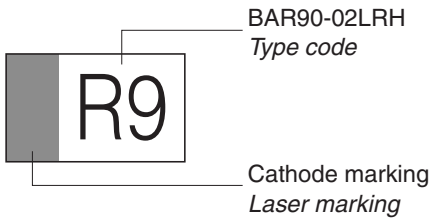
1) Dimension applies to plated terminal

Foot Print

For board assembly information please refer to Infineon website "Packages"

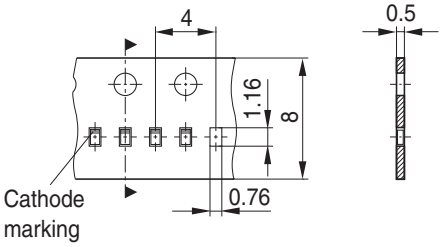


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel
Reel ø330 mm = 50.000 Pieces/Reel (optional)



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